

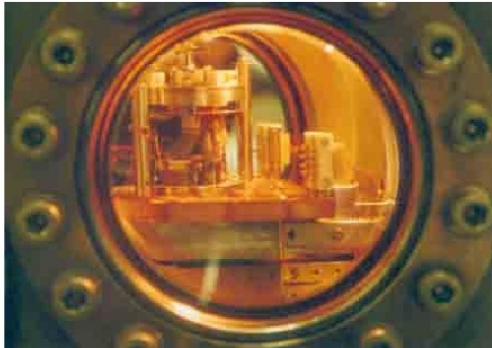


Thilo Reusch (Autor)

Cross-sectional Scanning Tunneling Microscopy of Au contacts on GaAs(110)

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Tunneling Microscopy
of Au contacts on GaAs(110)**



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